

## 9-11 GHz LOW NOISE AMPLIFIER

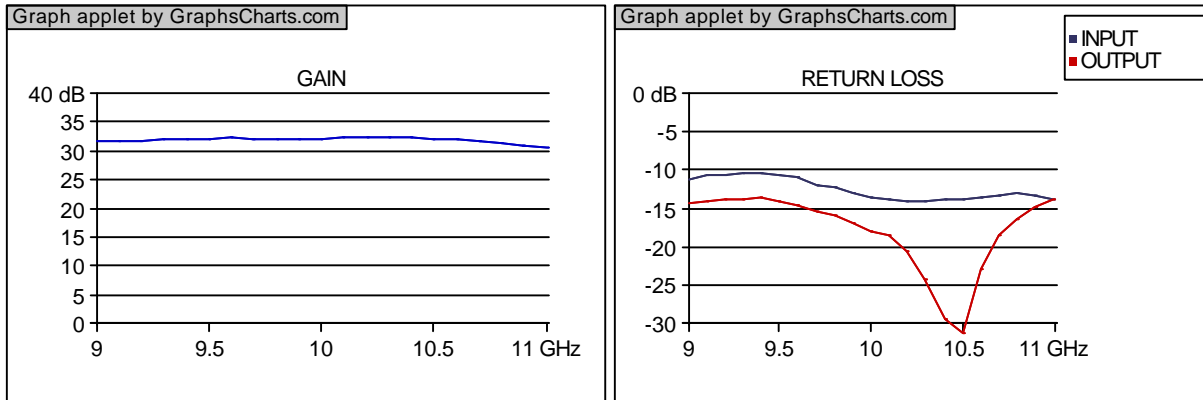
**Features:**

- Thin Film Hybrid MIC Process
- Field Replaceable RF Connectors

**Electrical Performance**

Parameter	Min.	Typ.	Max.	Unit	Note
Frequency	9		11	GHz	
Gain	30			dB	
Gain Flatness			1	dB(+/-)	
Power @ 1dB Gain Compression Point	13	15		dBm	
Noise Figure			2.2	dB	
VSWR Input			2		
VSWR Output			2		
Supplied Current			150	mA	
DC Supply Voltage	12		18	V	

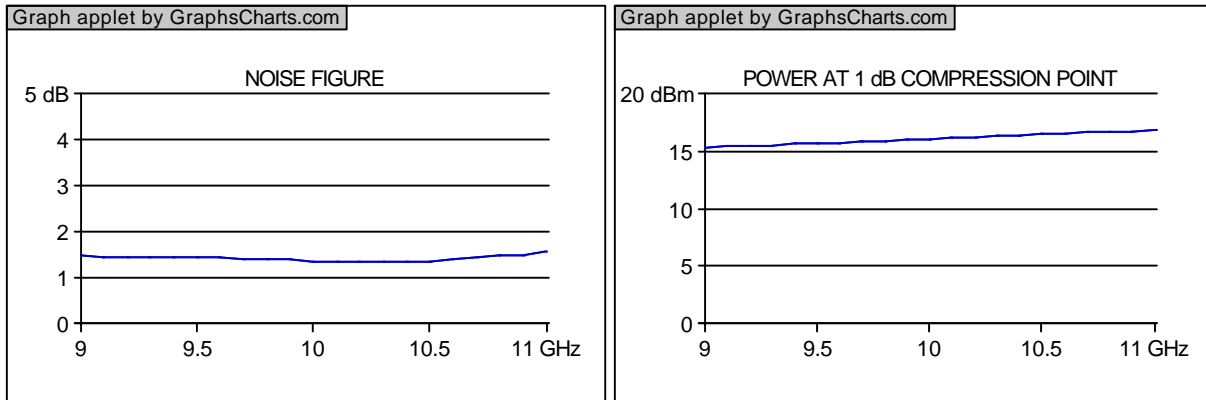
**Typical Test Data**



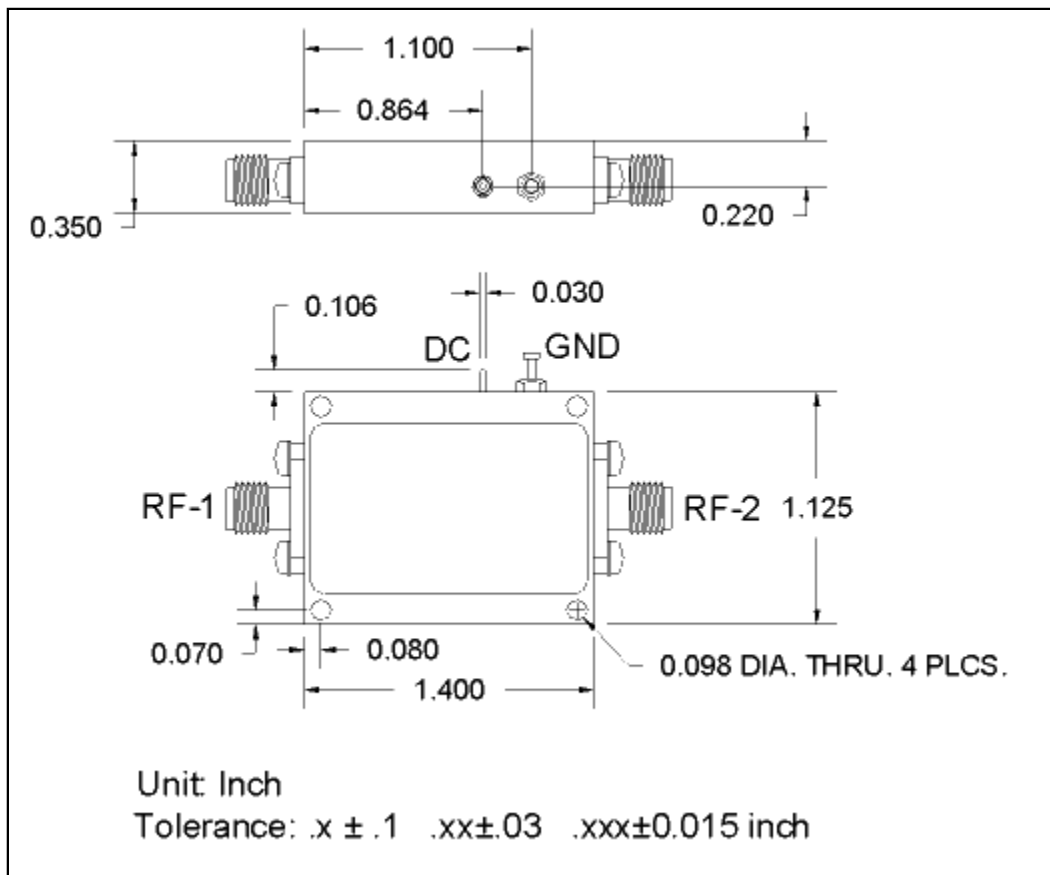
Updated: 5/23/2006

# NLC00512

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### Outline Drawing



Updated: 5/23/2006

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Connector	Type	Pin #	Pin Name	In/Out	Description
RF-1	SMA-F	1	IN	I	RF INPUT SIGNAL
RF-2	SMA-F	1	OUT	O	RF OUTPUT SIGNAL
DC	EMI Filter	1	+12 V	I	DC INPUT (+12 TO +18 V)
GND	GROUND LUG	1	GND	O	GROUND

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Nextec Microwave & RF, Inc [WWW.NEXTEC-RF.COM](http://WWW.NEXTEC-RF.COM)  
3010 Scott Blvd., Santa Clara, CA 95054  
(408) 727-1189 (408) 727-5915(Fax) [sales@nextec-rf.com](mailto:sales@nextec-rf.com)